

N-CHANNEL MOS FIELD EFFECT TRANSISTOR FOR SWITCHING

DESCRIPTION

The μ PA622TT is a switching device which can be driven directly by a 4.0 V power source.

This device features a low on-state resistance and excellent switching characteristics, and is suitable for applications such as power switch of portable machine and so on.

FEATURES

- 4.0 V drive available
- Low on-state resistance
- $R_{DS(on)1} = 82 \text{ m}\Omega \text{ MAX. (} V_{GS} = 10 \text{ V, } I_D = 1.5 \text{ A)}$
- $R_{DS(on)2} = 120 \text{ m}\Omega \text{ MAX. (} V_{GS} = 4.5 \text{ V, } I_D = 1.0 \text{ A)}$
- $R_{DS(on)3} = 139 \text{ m}\Omega \text{ MAX. (} V_{GS} = 4.0 \text{ V, } I_D = 1.0 \text{ A)}$

★ ORDERING INFORMATION

| PART NUMBER | PACKAGE |
|--------------------|-------------------|
| μ PA622TT-E1-A | 6 pin WSOF (1620) |
| μ PA622TT-E2-A | |

Remark "-A" indicates Pb-free (This product does not contain Pb in external electrode and other parts.).

"-E1" or "-E2" indicates the unit orientation.
(8 mm embossed carrier tape, 3000 pcs/reel)

Marking: WC

ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$)

| | | | |
|--|----------------|-------------|------------------|
| Drain to Source Voltage ($V_{GS} = 0 \text{ V}$) | V_{DSS} | 30 | V |
| Gate to Source Voltage ($V_{DS} = 0 \text{ V}$) | V_{GSS} | ± 20 | V |
| Drain Current (DC) | $I_{D(DC)}$ | ± 3.0 | A |
| Drain Current (pulse) | $I_{D(pulse)}$ | ± 12 | A |
| Total Power Dissipation | P_{T1} | 0.2 | W |
| Total Power Dissipation | P_{T2} | 1.3 | W |
| Channel Temperature | T_{ch} | 150 | $^\circ\text{C}$ |
| Storage Temperature | T_{stg} | -55 to +150 | $^\circ\text{C}$ |

Notes 1. Mounted on FR-4 board of $5000 \text{ mm}^2 \times 1.1 \text{ mm}$, $t \leq 5 \text{ sec}$.

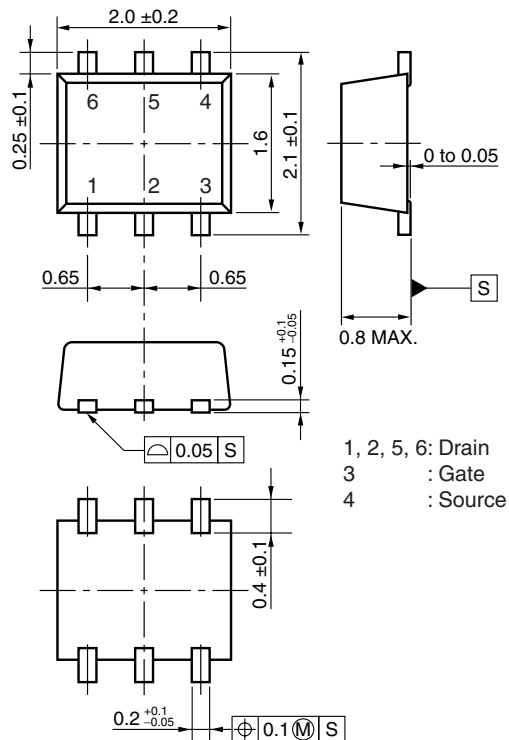
2. $PW \leq 10 \mu\text{s}$, Duty Cycle $\leq 1\%$

Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

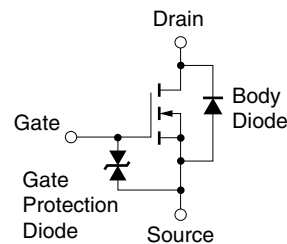
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PACKAGE DRAWING (Unit: mm)



EQUIVALENT CIRCUIT

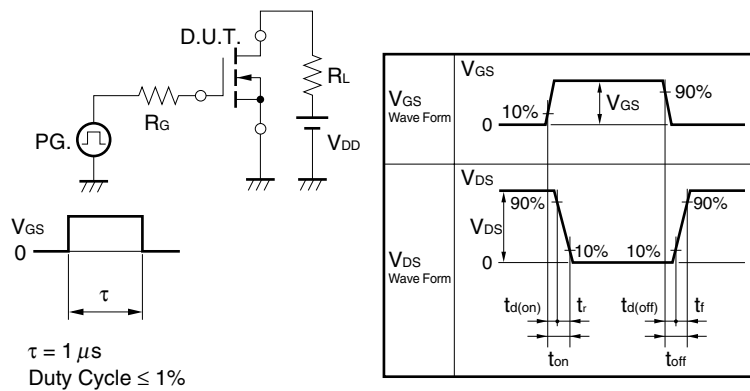


ELECTRICAL CHARACTERISTICS (T_A = 25°C)

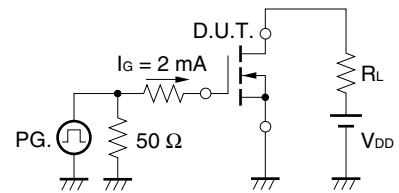
| CHARACTERISTICS | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|---|----------------------|---|------|------|------|------|
| Zero Gate Voltage Drain Current | I _{DSS} | V _{DS} = 30 V, V _{GS} = 0 V | | | 10 | μA |
| ★ Gate Leakage Current | I _{GSS} | V _{GS} = ±16 V, V _{DS} = 0 V | | | ±10 | μA |
| Gate Cut-off Voltage | V _{GS(off)} | V _{DS} = 10 V, I _D = 1.0 mA | 1.5 | 2.0 | 2.5 | V |
| Forward Transfer Admittance ^{Note} | y _{fs} | V _{DS} = 10 V, I _D = 1.5 A | 0.5 | 2.1 | | S |
| Drain to Source On-state Resistance ^{Note} | R _{DS(on)1} | V _{GS} = 10 V, I _D = 1.5 A | | 65 | 82 | mΩ |
| | R _{DS(on)2} | V _{GS} = 4.5 V, I _D = 1.0 A | | 90 | 120 | mΩ |
| | R _{DS(on)3} | V _{GS} = 4.0 V, I _D = 1.0 A | | 104 | 139 | mΩ |
| Input Capacitance | C _{iss} | V _{DS} = 10 V | | 155 | | pF |
| Output Capacitance | C _{oss} | V _{GS} = 0 V | | 45 | | pF |
| Reverse Transfer Capacitance | C _{rss} | f = 1.0 MHz | | 27 | | pF |
| Turn-on Delay Time | t _{d(on)} | V _{DD} = 15 V, I _D = 1.5 A | | 10 | | ns |
| Rise Time | t _r | V _{GS} = 10 V | | 28 | | ns |
| Turn-off Delay Time | t _{d(off)} | R _G = 10 Ω | | 75 | | ns |
| Fall Time | t _f | | | 50 | | ns |
| Total Gate Charge | Q _G | V _{DD} = 24 V | | 3.8 | | nC |
| Gate to Source Charge | Q _{GS} | V _{GS} = 10 V | | 0.7 | | nC |
| Gate to Drain Charge | Q _{GD} | I _D = 3.0 A | | 1.3 | | nC |
| Body Diode Forward Voltage ^{Note} | V _{F(S-D)} | I _F = 3.0 A, V _{GS} = 0 V | | 0.90 | | V |

Note Pulsed

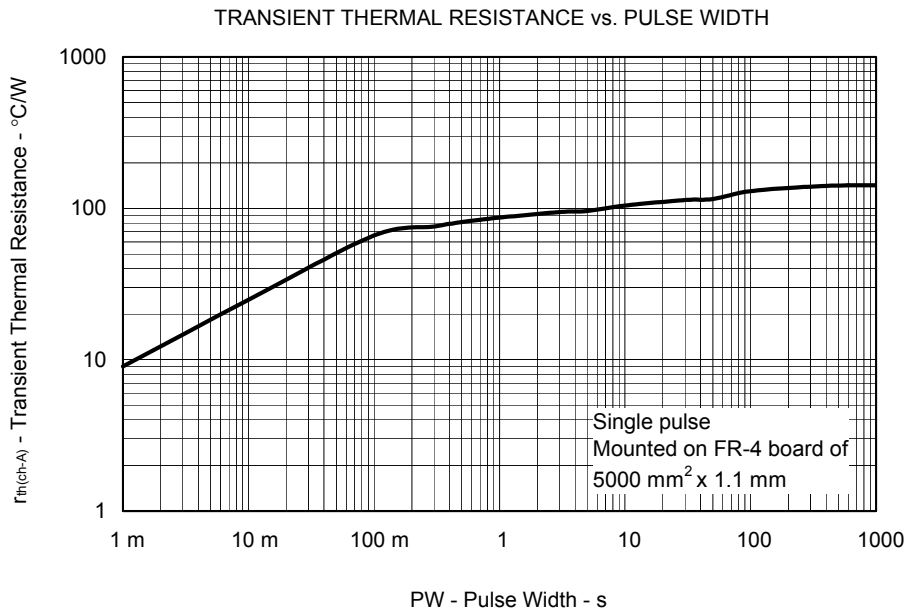
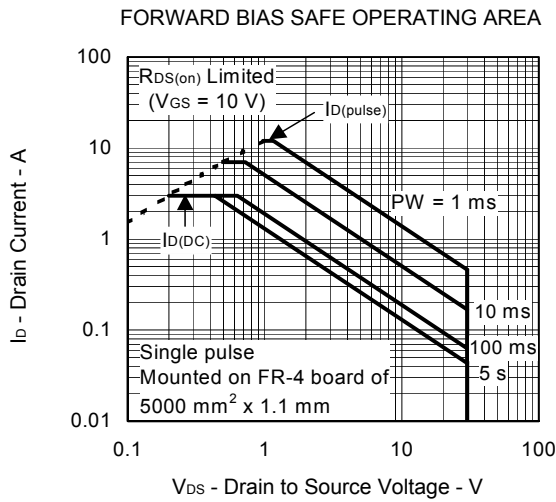
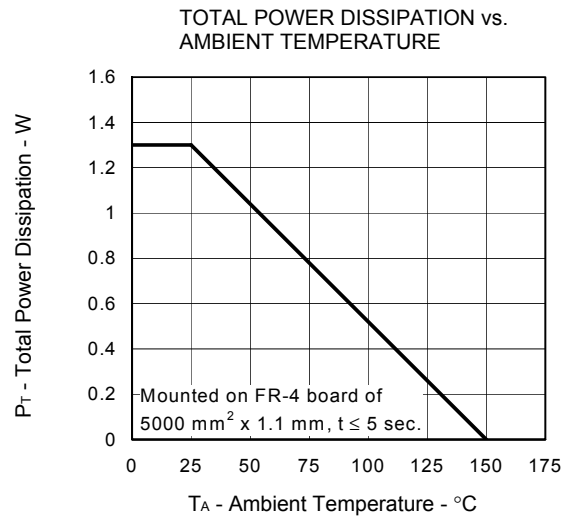
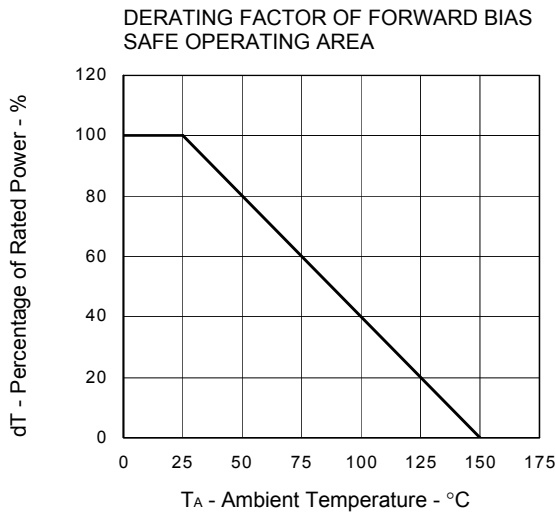
TEST CIRCUIT 1 SWITCHING TIME



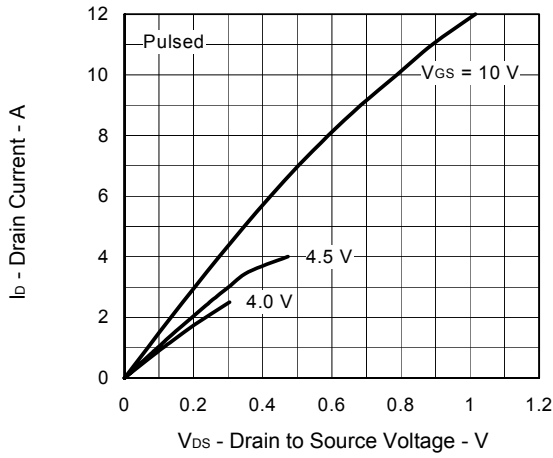
TEST CIRCUIT 2 GATE CHARGE



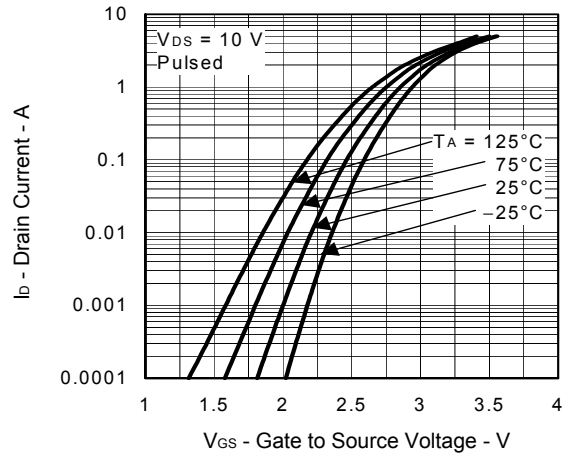
TYPICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$)



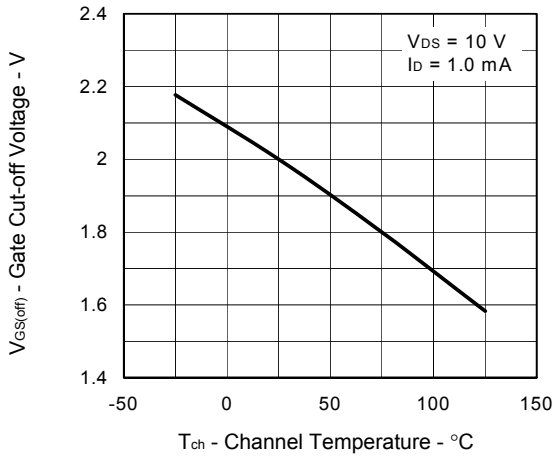
DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE



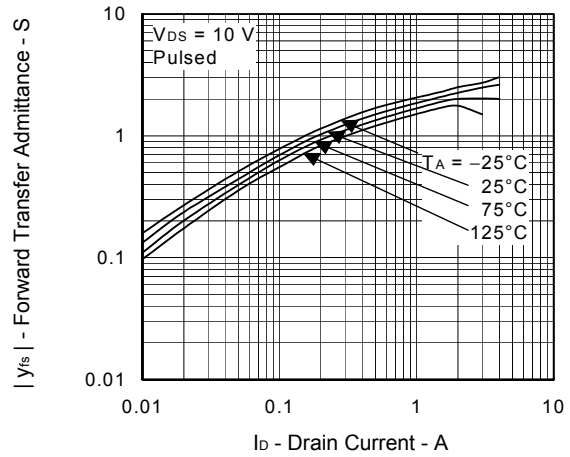
FORWARD TRANSFER CHARACTERISTICS



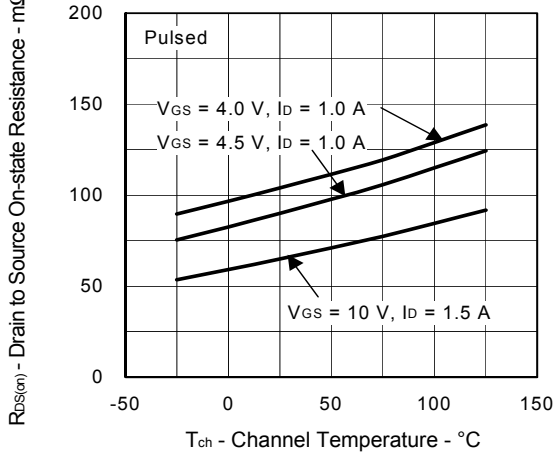
GATE CUT-OFF VOLTAGE vs. CHANNEL TEMPERATURE



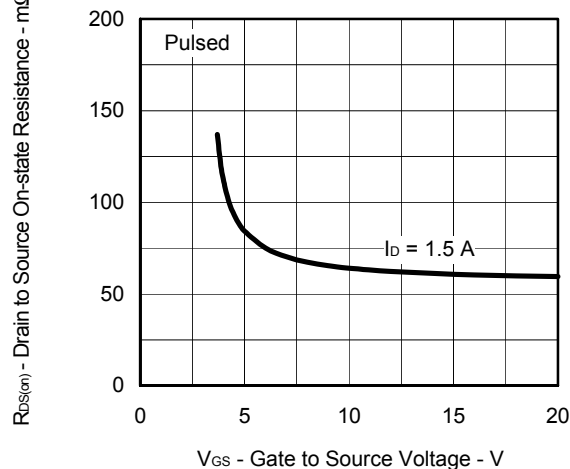
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT

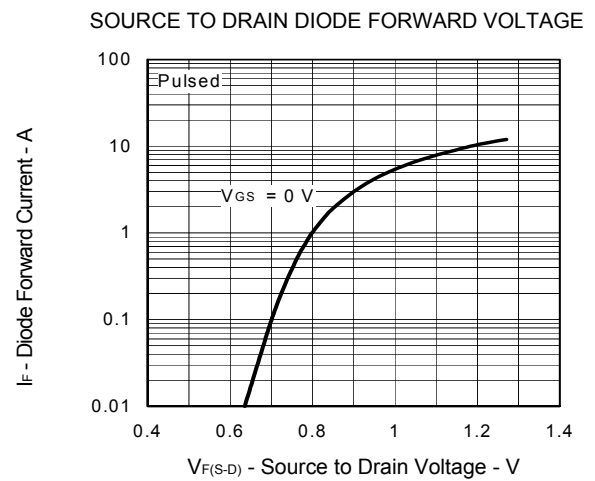
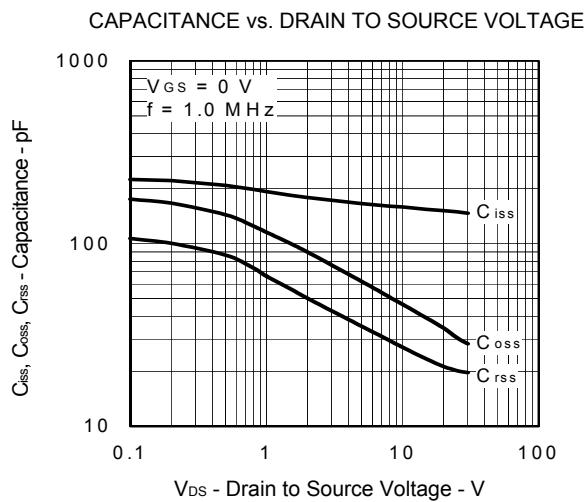
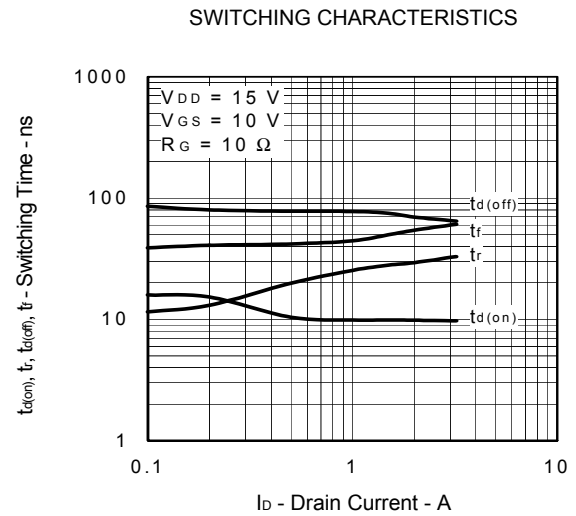
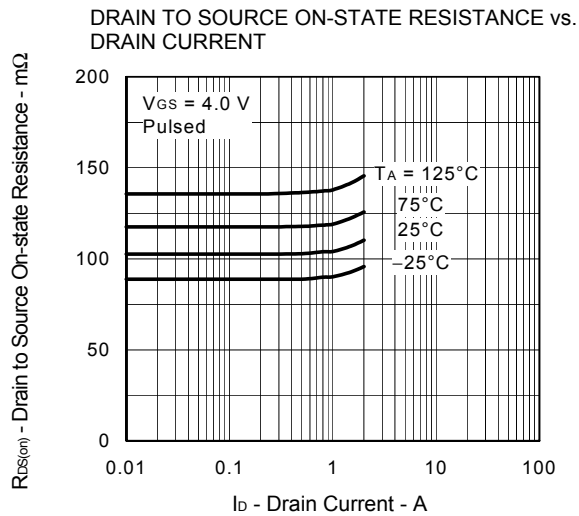
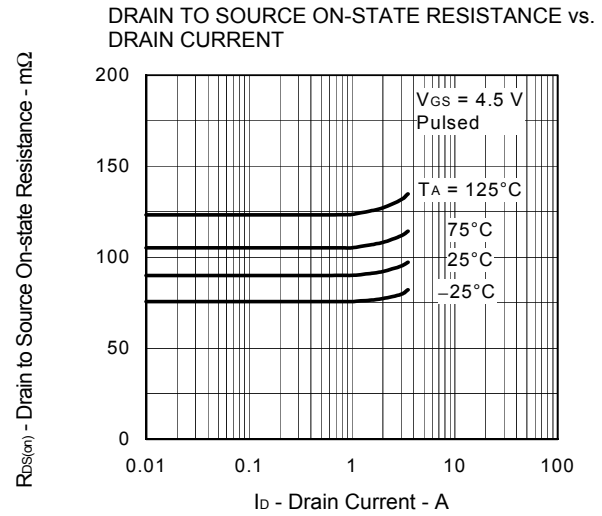
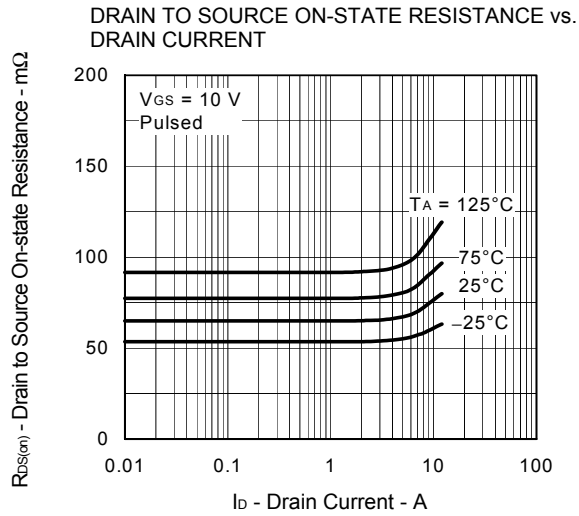


DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE

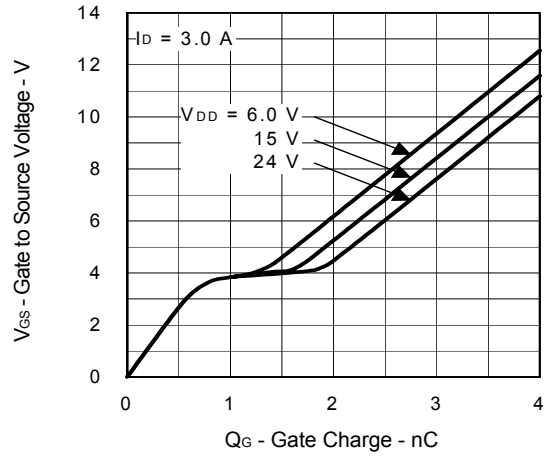


DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE





DYNAMIC INPUT/OUTPUT CHARACTERISTICS



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